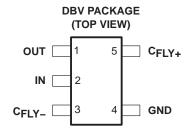
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#### features

- Qualified for Automotive Applications
- Inverts Input Supply Voltage
- Up to 60-mA Output Current
- Only Three Small 1-μF Ceramic Capacitors Needed
- Input Voltage Range From 1.6 V to 5.5 V
- PowerSave-Mode for Improved Efficiency at Low Output Currents (TPS60400)
- Device Quiescent Current Typical 100 μA
- Integrated Active Schottky-Diode for Start-Up Into Load
- Small 5-Pin SOT23 Package
- Evaluation Module Available TPS60400EVM-178

### applications

- LCD Bias
- GaAs Bias for RF Power Amps
- Sensor Supply in Portable Instruments
- Bipolar Amplifier Supply



## description

The TPS6040x is a family of devices that generate an unregulated negative output voltage from an input voltage ranging from 1.6 V to 5.5 V. The devices are typically supplied by a preregulated supply rail of 5 V or 3.3 V. Due to its wide input voltage range, two or three NiCd, NiMH, or alkaline battery cells, as well as one Li-lon cell can also power them.

Only three external  $1-\mu F$  capacitors are required to build a complete dc/dc charge pump inverter. Assembled in a 5-pin SOT23 package, the complete converter can be built on a 50-mm<sup>2</sup> board area. Additional board area and component count reduction is achieved by replacing the Schottky diode that is typically needed for start-up into load by integrated circuitry.

The TPS6040x can deliver a maximum output current of 60 mA with a typical conversion efficiency of greater than 90% over a wide output current range. Three device options with 20-kHz, 50-kHz, and 250-kHz fixed frequency operation are available. One device comes with a variable switching frequency to reduce operating current in applications with a wide load range and enables the design with low-value capacitors.

#### **AVAILABLE OPTIONS**<sup>†</sup>

PART NUMBER	MARKING DBV PACKAGE <sup>‡</sup>	TYPICAL FLYING CAPACITOR $[\mu F]$	FEATURE
TPS60400QDBVRQ1	AWP	1	Variable switching frequency 50 kHz–250 kHz
TPS60401QDBVRQ1	AWQ	10	Fixed frequency 20 kHz
TPS60402QDBVRQ1	AWR	3.3	Fixed frequency 50 kHz
TPS60403QDBVRQ1	AWS	1	Fixed frequency 250 kHz

<sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



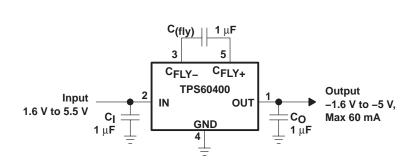
<sup>‡</sup> Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

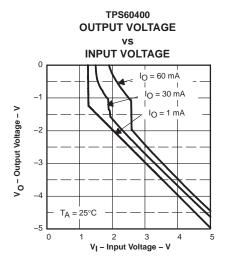
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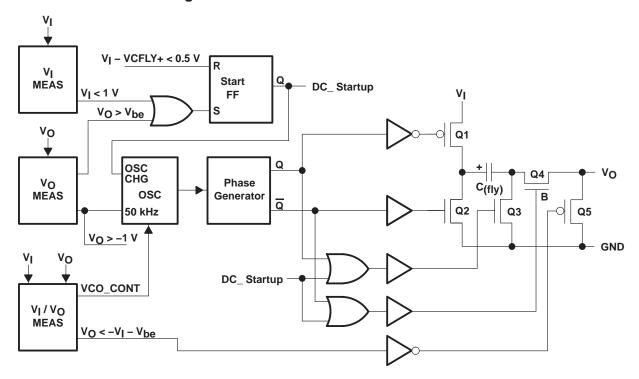
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications. These devices have limited built-in ESD protection.

## typical application circuit





## TPS60400 functional block diagram



#### **Terminal Functions**

TERMI	NAL		DECODINE
NAME	NO.	1/0	DESCRIPTION
C <sub>FLY+</sub>	5		Positive terminal of the flying capacitor C <sub>(fly)</sub>
C <sub>FLY</sub> _	3		Negative terminal of the flying capacitor C <sub>(fly)</sub>
GND	4		Ground
IN	2	I	Supply input. Connect to an input supply in the 1.6-V to 5.5-V range. Bypass IN to GND with a capacitor that has the same value as the flying capacitor.
OUT	1	0	Power output with $V_O = -V_I$ Bypass OUT to GND with the output filter capacitor $C_O$ .

## detailed description

### operating principle

The TPS60400, TPS60401 charge pumps invert the voltage applied to their input. For the highest performance, use low equivalent series resistance (ESR) capacitors (e.g., ceramic). During the first half-cycle, switches S2 and S4 open, switches S1 and S3 close, and capacitor ( $C_{(fly)}$ ) charges to the voltage at  $V_I$ . During the second half-cycle, S1 and S3 open, S2 and S4 close. This connects the positive terminal of  $C_{(fly)}$  to GND and the negative to  $V_O$ . By connecting  $C_{(fly)}$  in parallel,  $C_O$  is charged negative. The actual voltage at the output is more positive than  $-V_I$ , since switches S1–S4 have resistance and the load drains charge from  $C_O$ .

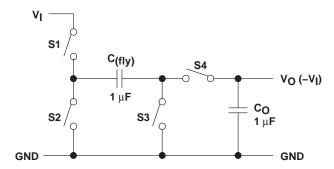


Figure 1. Operating Principle

#### charge-pump output resistance

The TPS6040x devices are not voltage regulators. The charge pumps output source resistance is approximately 15  $\Omega$  at room temperature (with V<sub>I</sub> = 5 V), and V<sub>O</sub> approaches –5 V when lightly loaded. V<sub>O</sub> will droop toward GND as load current increases.

$$V_{O} = -(V_{I} - R_{O} \times I_{O})$$

$$R_{O} \approx \frac{1}{f \text{osc} \times C_{(fly)}} + 4(2R_{SWITCH} + ESR_{CFLY}) + ESR_{CO}$$

$$R_{O} = \text{output resistance of the converter}$$
(1)



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## detailed description (continued)

#### efficiency considerations

The power efficiency of a switched-capacitor voltage converter is affected by three factors: the internal losses in the converter IC, the resistive losses of the capacitors, and the conversion losses during charge transfer between the capacitors. The internal losses are associated with the IC's internal functions, such as driving the switches, oscillator, etc. These losses are affected by operating conditions such as input voltage, temperature, and frequency. The next two losses are associated with the voltage converter circuit's output resistance. Switch losses occur because of the on-resistance of the MOSFET switches in the IC. Charge-pump capacitor losses occur because of their ESR. The relationship between these losses and the output resistance is as follows:

PCAPACITOR LOSSES + PCONVERSION LOSSES = Io<sup>2</sup> × Ro

R<sub>SWITCH</sub> = resistance of a single MOSFET-switch inside the converter f<sub>OSC</sub> = oscillator frequency

The first term is the effective resistance from an ideal switched-capacitor circuit. Conversion losses occur during the charge transfer between  $C_{(f|v)}$  and  $C_O$  when there is a voltage difference between them. The power loss is:

$$P_{\text{CONV.LOSS}} = \left[\frac{1}{2} \times C_{\text{(fly)}} \left(V_{\text{I}}^2 - V_{\text{O}}^2\right) + \frac{1}{2}C_{\text{O}} \left(V_{\text{RIPPLE}}^2 - 2V_{\text{O}}V_{\text{RIPPLE}}\right)\right] \times f_{\text{osc}}$$
(2)

The efficiency of the TPS6040x devices is dominated by their quiescent supply current at low output current and by their output impedance at higher current.

$$\eta \cong \frac{I_O}{I_O + I_Q} \left( 1 - \frac{I_O \times R_O}{V_I} \right)$$

Where,  $I_Q$  = quiescent current.

#### capacitor selection

To maintain the lowest output resistance, use capacitors with low ESR (see Table 1). The charge-pump output resistance is a function of  $C_{(fly)}$ 's and  $C_O$ 's ESR. Therefore, minimizing the charge-pump capacitor's ESR minimizes the total output resistance. The capacitor values are closely linked to the required output current and the output noise and ripple requirements. It is possible to only use 1- $\mu$ F capacitors of the same type.

#### input capacitor (C<sub>I</sub>)

Bypass the incoming supply to reduce its ac impedance and the impact of the TPS6040x switching noise. The recommended bypassing depends on the circuit configuration and where the load is connected. When the inverter is loaded from OUT to GND, current from the supply switches between 2 x  $I_O$  and zero. Therefore, use a large bypass capacitor (e.g., equal to the value of  $C_{(fly)}$ ) if the supply has high ac impedance. When the inverter is loaded from IN to OUT, the circuit draws  $2 \times I_O$  constantly, except for short switching spikes. A 0.1- $\mu$ F bypass capacitor is sufficient.

## flying capacitor (C(fly))

Increasing the flying capacitor's size reduces the output resistance. Small values increases the output resistance. Above a certain point, increasing  $C_{(fly)}$ 's capacitance has a negligible effect, because the output resistance becomes dominated by the internal switch resistance and capacitor ESR.



## detailed description (continued)

## output capacitor (C<sub>O</sub>)

Increasing the output capacitor's size reduces the output ripple voltage. Decreasing its ESR reduces both output resistance and ripple. Smaller capacitance values can be used with light loads if higher output ripple can be tolerated. Use the following equation to calculate the peak-to-peak ripple.

$$V_{O(ripple)} = \frac{I_{O}}{f_{OSC} \times C_{O}} + 2 \times I_{O} \times ESR_{CO}$$

**Table 1. Recommended Capacitor Values** 

DEVICE	ν <sub>Ι</sub> [۷]	I <sub>O</sub> [mA]	C <sub>[</sub> [μ <b>F</b> ]	C <sub>(fly)</sub> [μF]	C <sub>O</sub> [μF]
TPS60400	1.85.5	60	1	1	1
TPS60401	1.85.5	60	10	10	10
TPS60402	1.85.5	60	3.3	3.3	3.3
TPS60403	1.85.5	60	1	1	1

**Table 2. Recommended Capacitors** 

MANUFACTURER	PART NUMBER	SIZE	CAPACITANCE	TYPE
Taiyo Yuden	EMK212BJ474MG	0805	0.47 μF	Ceramic
	LMK212BJ105KG	0805	1 μF	Ceramic
	LMK212BJ225MG	0805	2.2 μF	Ceramic
	EMK316BJ225KL	1206	2.2 μF	Ceramic
	LMK316BJ475KL	1206	4.7 μF	Ceramic
	JMK316BJ106KL	1206	10 μF	Ceramic
TDK	C2012X5R1C105M	0805	1 μF	Ceramic
	C2012X5R1A225M	0805	2.2 μF	Ceramic
	C2012X5R1A335M	0805	3.3 μF	Ceramic

Table 3 contains a list of manufacturers of the recommended capacitors. Ceramic capacitors will provide the lowest output voltage ripple because they typically have the lowest ESR-rating.

**Table 3. Recommended Capacitor Manufacturers** 

MANUFACTURER	CAPACITOR TYPE	INTERNET
Taiyo Yuden	X7R/X5R ceramic	www.t-yuden.com
TDK	X7R/X5R ceramic	www.component.tdk.com
Vishay	X7R/X5R ceramic	www.vishay.com
Kemet	X7R/X5R ceramic	www.kemet.com

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## absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Voltage range:	IN to GND	0.3 V to 5.5 V
0 0	OUT to GND	–5 V to 0.3 V
	C <sub>FLY</sub> _ to GND	0.3 V to $(V_O - 0.3 V)$
	C <sub>FLY+</sub> to GND	$-0.3 \text{ V to } (V_1 + 0.3 \text{ V})$
Continuous pow	er dissipation	See Dissipation Rating Table
Continuous outp	out current	80 mA
Electrostatic Dis	charge (Machine Model)	passed 50 V
	(Human Body Model)	passed 2 kV
	(Charged Device Model)	passed 1 kV
Storage tempera	ature range, T <sub>stg</sub>	–55°C to 150°C
Maximum junction	on temperature, T <sub>J</sub>	150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> < 25°C	DERATING FACTOR	T <sub>A</sub> = 70°C	T <sub>A</sub> = 85°C
	POWER RATING	ABOVE T <sub>A</sub> = 25°C	POWER RATING	POWER RATING
DBV	437 mW	3.5 mW/°C	280 mW	227 mW

## recommended operating conditions

	MIN	NOM	MAX	UNIT
Input voltage range, V <sub>I</sub>	1.8		5.25	V
Output current range at OUT, IO			60	mA
Input capacitor, C <sub>I</sub>	0	C <sub>(fly)</sub>		μF
Flying capacitor, C <sub>(fly)</sub>		1		μF
Output capacitor, CO		1	100	μF
Operating junction temperature, T <sub>J</sub>	-40		125	°C



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# electrical characteristics at $C_I = C_{(fly)} = C_O$ (according to Table 1), $T_J = -40^{\circ}C$ to $125^{\circ}C$ , $V_I = 5$ V over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
.,	O. and be self-order		At $T_J = -40^{\circ}C$ t	o 125°C, R <sub>L</sub> = 5 kΩ	1.8		5.25	V
VI	Supply voltage range		At $T_C \ge 0^{\circ}C$ ,	$R_L = 5 \text{ k}\Omega$	1.6			V
IO	Maximum output current at VO				60			mA
VO	Output voltage					-V <sub>I</sub>		V
		TPS60400		$C_{(fly)} = 1 \mu F, C_O = 2.2 \mu F$		35		
\/	Outrout valta as visuals	TPS60401		$C_{(fly)} = C_O = 10 \mu\text{F}$		20		> /
V <sub>P</sub> -P	Output voltage ripple	TPS60402	$I_O = 5 \text{ mA}$	$C_{(fly)} = C_O = 3.3 \mu\text{F}$		20		mV <sub>P</sub> _P
		TPS60403		$C_{(fly)} = C_O = 1 \mu F$		15		
		TPS60400				125	270	
		TPS60401	At V <sub>I</sub> = 5 V			65	190	μΑ
		TPS60402				120	270	
	Quiescent current (no-load input	TPS60403				425	700	ı
IQ	current)	TPS60400					210	
		TPS60401	At T <sub>J</sub> ≤ 60°C, V <sub>I</sub> = 5 V				135	μΑ
		TPS60402					210	
		TPS60403					640	
		TPS60400	VCO version		25	50-250	375	
		TPS60401			10	20	30	1.11-
fosc	Internal switching frequency	TPS60402			25	50	75	kHz
		TPS60403			115	250	325	
		TPS60400	$C_I = C_{(fly)} = C_C$	<sub>)</sub> = 1 μF		12	15	
	Impedance at 25°C Vi = 5 V	TPS60401	$C_I = C_{(f y)} = C_O = 10 \mu\text{F}$			12	15	
	Impedance at 25°C, V <sub>I</sub> = 5 V	TPS60402	$C_I = C_{(fly)} = C_C$	) = 3.3 μF		12	15	Ω
		TPS60403	$C_I = C_{(fly)} = C_C$	) = 1 μF		12	15	

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## TYPICAL CHARACTERISTICS

## **Table of Graphs**

			FIGURE
η	Efficiency	vs Output current at 3.3 V, 5 V TPS60400, TPS60401, TPS60402, TPS60403	2, 3
lį	Input current	vs Output current TPS60400, TPS60401, TPS60402, TPS60403	4, 5
IS	Supply current	vs Input voltage TPS60400, TPS60401, TPS60402, TPS60403	6, 7
	Output resistance	vs Input voltage at $-40^{\circ}$ C, $0^{\circ}$ C, $25^{\circ}$ C, $85^{\circ}$ C TPS60400, $C_I = C_{(fly)} = C_O = 1 \mu\text{F}$ TPS60401, $C_I = C_{(fly)} = C_O = 10 \mu\text{F}$ TPS60402, $C_I = C_{(fly)} = C_O = 3.3 \mu\text{F}$ TPS60403, $C_I = C_{(fly)} = C_O = 1 \mu\text{F}$	8, 9, 10, 11
VO	Output voltage	vs Output current at 25°C, V <sub>IN</sub> = 1.8 V, 2.5 V, 3.3 V, 5 V TPS60400, C <sub>I</sub> = C <sub>(fly)</sub> = C <sub>O</sub> = 1 $\mu$ F TPS60401, C <sub>I</sub> = C <sub>(fly)</sub> = C <sub>O</sub> = 10 $\mu$ F TPS60402, C <sub>I</sub> = C <sub>(fly)</sub> = C <sub>O</sub> = 3.3 $\mu$ F TPS60403, C <sub>I</sub> = C <sub>(fly)</sub> = C <sub>O</sub> = 1 $\mu$ F	12, 13, 14, 15
fosc	Oscillator frequency	vs Temperature at V <sub>I</sub> = 1.8 V, 2.5 V, 3.3 V, 5 V TPS60400, TPS60401, TPS60402, TPS60403	16, 17, 18, 19
fosc	Oscillator frequency	vs Output current TPS60400 at 2 V, 3.3 V, 5.0 V	20
	Output ripple and noise	$\begin{array}{c} V_I = 5 \text{ V, } I_O = 30 \text{ mA, } C_I = C_{(fly)} = C_O = 1  \mu\text{F (TPS60400)} \\ V_I = 5 \text{ V, } I_O = 30 \text{ mA, } C_I = C_{(fly)} = C_O = 10  \mu\text{F (TPS60401)} \\ V_I = 5 \text{ V, } I_O = 30 \text{ mA, } C_I = C_{(fly)} = C_O = 3.3  \mu\text{F (TPS60402)} \\ V_I = 5 \text{ V, } I_O = 30 \text{ mA, } C_I = C_{(fly)} = C_O = 1  \mu\text{F (TPS60403)} \end{array}$	21, 22

## ٧S **OUTPUT CURRENT** 100 TPS60400 $V_I = 5 V$ 95 TPS60401 $V_I = 5 V$ 90 Efficiency - % 85 TPS60401 $V_{I} = 3.3 V$ 80 75 TPS60400 70 $V_{I} = 3.3 V$ 65 $T_A = 25^{\circ}C$ 60

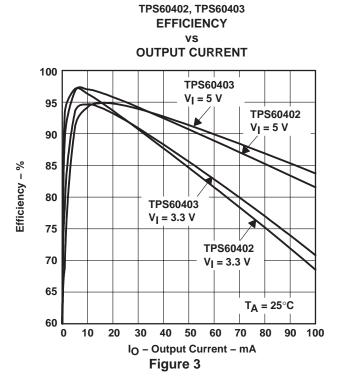
40 50 60 70 80

Figure 2

IO - Output Current - mA

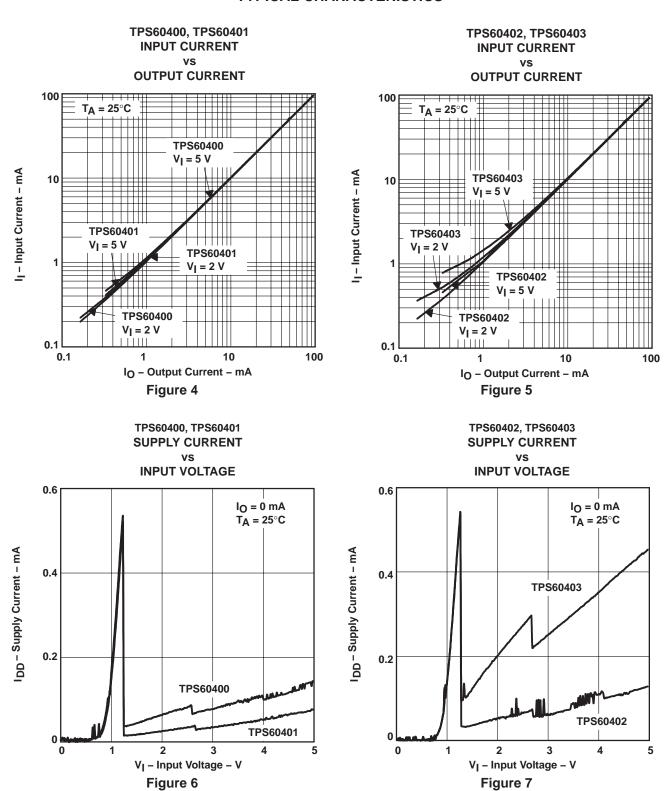
TPS60400, TPS60401

**EFFICIENCY** 

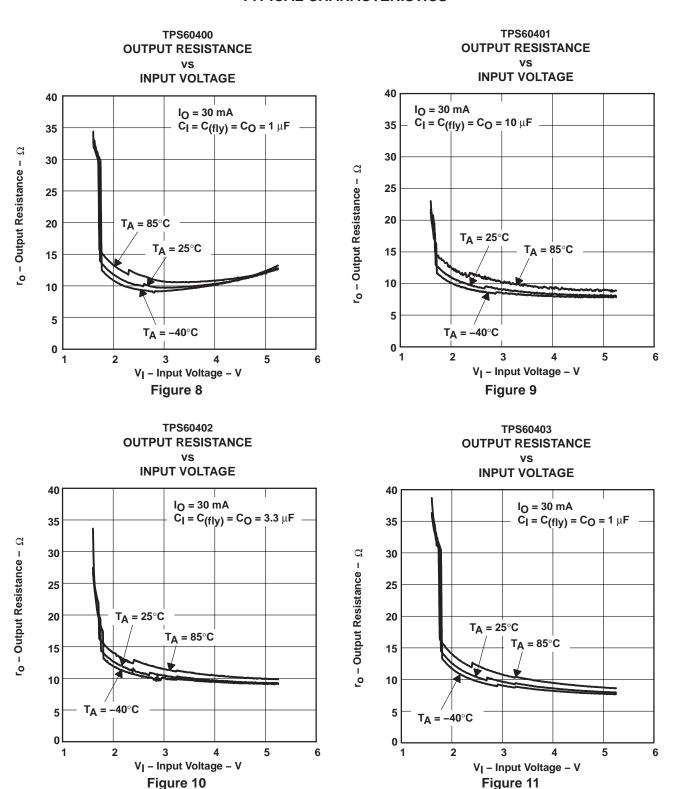


90 100

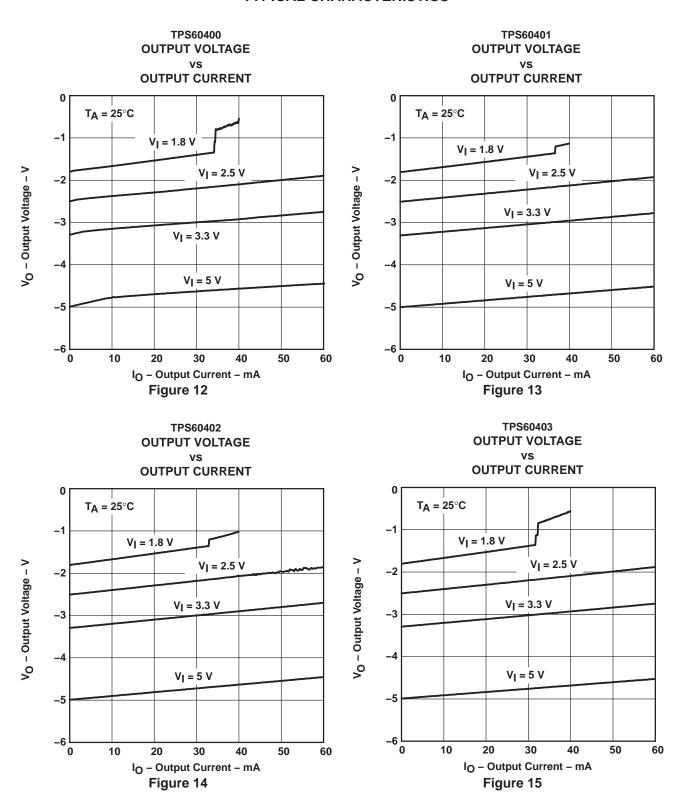
10 20

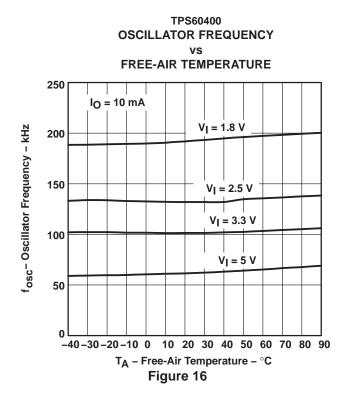


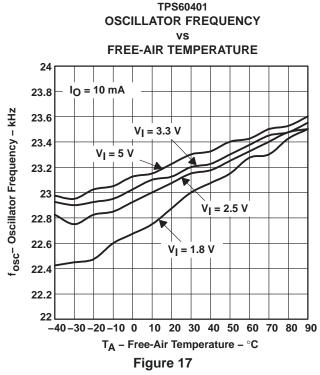


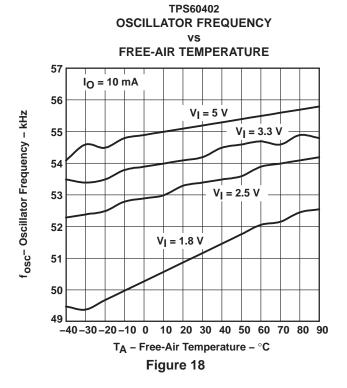


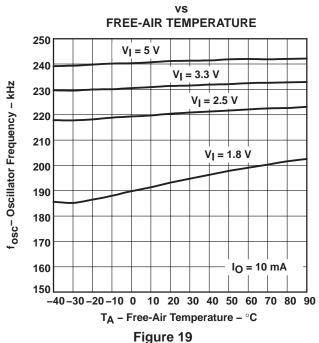






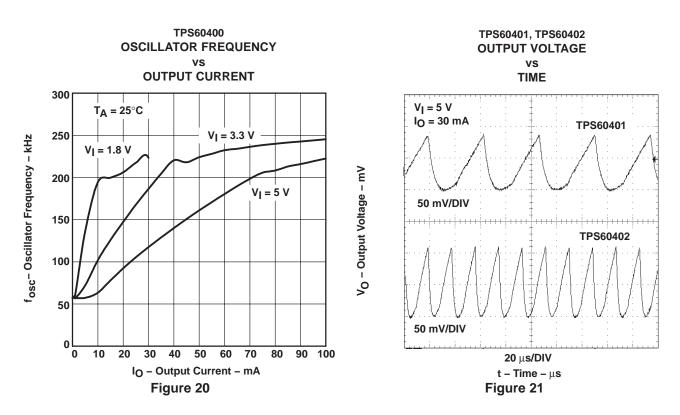


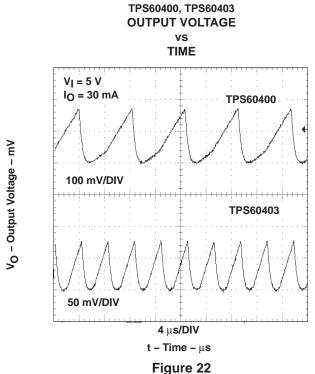




**TPS60403** 

**OSCILLATOR FREQUENCY** 





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#### **APPLICATION INFORMATION**

## voltage inverter

The most common application for these devices is a charge-pump voltage inverter (see Figure 23). This application requires only two external components; capacitors  $C_{(fly)}$  and  $C_{O}$ , plus a bypass capacitor, if necessary. See the *capacitor selection* section for suggested capacitor types.

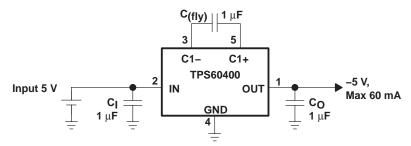


Figure 23. Typical Operating Circuit

For the maximum output current and best performance, three ceramic capacitors of 1  $\mu$ F (TPS60400, TPS60403) are recommended. For lower currents or higher allowed output voltage ripple, other capacitors can also be used. It is recommended that the output capacitors has a minimum value of 1  $\mu$ F. With flying capacitors lower than 1  $\mu$ F, the maximum output power will decrease.

## **RC-post filter**

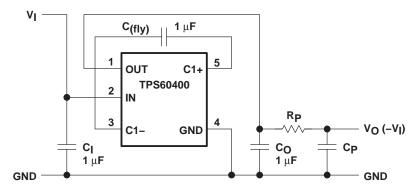


Figure 24. TPS60400 and TPS60401 With RC-Post Filter

An output filter can easily be formed with a resistor (R<sub>P</sub>) and a capacitor (C<sub>P</sub>). Cutoff frequency is given by:

$$f_{\rm C} = \frac{1}{2\pi R_{\rm p} C_{\rm p}} \quad (1)$$

and ratio V<sub>O</sub>/V<sub>OUT</sub> is:

$$\left| \frac{V_{O}}{V_{OUT}} \right| = \frac{1}{\sqrt{1 + \left(2\pi f R_{P} C_{P}\right)^{2}}} \quad (2)$$

with R<sub>P</sub> = 50 
$$\Omega$$
, C<sub>P</sub> = 0.1  $\mu$ F and f = 250 kHz:  $\left|\frac{V_O}{V_{OUT}}\right|$  = 0.125

The formula refers only to the relation between output and input of the ac ripple voltages of the filter.

## **LC-post filter**

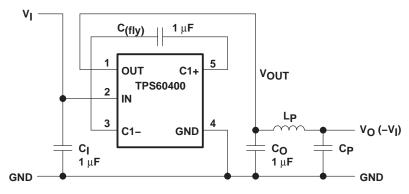


Figure 25. LC-Post Filter

Figure 25 shows a configuration with a LC-post filter to further reduce output ripple and noise.

Table 4. Measurement Results on the TPS60400 (Typical)

V <sub>I</sub> [V]	<sup>I</sup> O(2) [mA]	C <sub>I</sub> [μF]	C <sub>(fly)</sub> [μF]	C <sub>O</sub> [μF]	L <sub>P</sub> [μH]	<b>C</b> P [μ <b>F</b> ]	BW = 500 MHz VPOUT	BW = 20 MHz VPOUT	V <sub>POUT</sub> VACeff [mV]
[4]	الحسا	CERAMIC	CERAMIC	CERAMIC	μιι	CERAMIC	V <sub>P-P</sub> [mV]		
5	60	1	1	1			320	240	65
5	60	1	1	2.2			120	240	32
5	60	1	1	1		0.1 (X7R)	260	200	58
5	60	1	1	1	0.1	0.1 (X7R)	220	200	60
5	60	1	1	2.2	0.1	0.1 (X7R)	120	100	30
5	60	1	1	10	0.1	0.1 (X7R)	50	28	8

## rail splitter

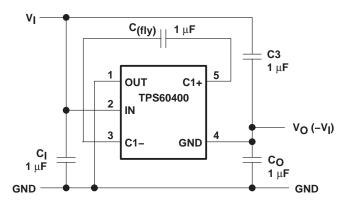


Figure 26. TPS60400 as a High-Efficiency Rail Splitter

A switched-capacitor voltage inverter can be configured as a high efficiency rail-splitter. This circuit provides a bipolar power supply that is useful in battery powered systems to supply dual-rail ICs, like operational amplifiers. Moreover, the SOT23-5 package and associated components require very little board space.

After power is applied, the flying capacitor ( $C_{(fly)}$ ) connects alternately across the output capacitors  $C_3$  and  $C_O$ . This equalizes the voltage on those capacitors and draws current from  $V_I$  to  $V_O$  as required to maintain the output at 1/2  $V_I$ .

The maximum input voltage between  $V_I$  and GND in the schematic (or between IN and OUT at the device itself) must not exceed 6.5 V.

#### combined doubler/inverter

In the circuit of Figure 27, capacitors  $C_I$ ,  $C_{(fly)}$ , and  $C_O$  form the inverter, while C1 and C2 form the doubler. C1 and  $C_{(fly)}$  are the flying capacitors;  $C_O$  and C2 are the output capacitors. Because both the inverter and doubler use part of the charge-pump circuit, loading either output causes both outputs to decline toward GND. Make sure the sum of the currents drawn from the two outputs does not exceed 60 mA. The maximum output current at  $V_{(DOS)}$  must not exceed 30 mA. If the negative output is loaded, this current must be further reduced.

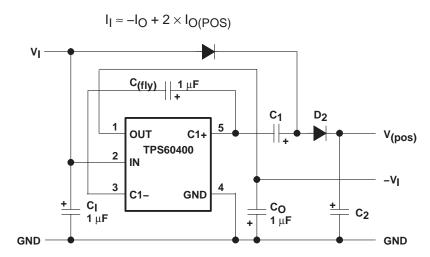


Figure 27. TPS60400 as Doubler/Inverter

### cascading devices

Two devices can be cascaded to produce an even larger negative voltage (see Figure 28). The unloaded output voltage is normally  $-2 \times V_I$ , but this is reduced slightly by the output resistance of the first device multiplied by the quiescent current of the second. When cascading more than two devices, the output resistance rises dramatically.

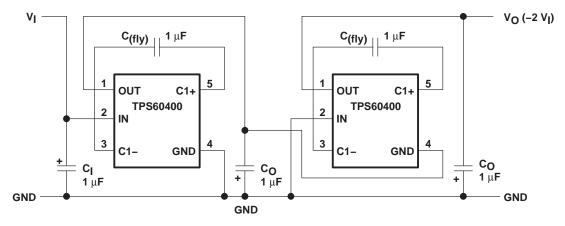


Figure 28. Doubling Inverter

## paralleling devices

Paralleling multiple TPS6040xs reduces the output resistance. Each device requires its own flying capacitor  $(C_{(fly)})$ , but the output capacitor  $(C_O)$  serves all devices (see Figure 29). Increase  $C_O$ 's value by a factor of n, where n is the number of parallel devices. Equation 1 shows the equation for calculating output resistance.

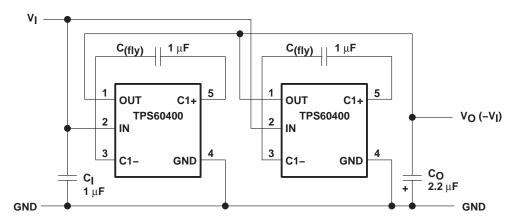


Figure 29. Paralleling Devices

## active-Schottky diode

For a short period of time, when the input voltage is applied, but the inverter is not yet working, the output capacitor is charged positive by the load. To prevent the output being pulled above GND, a Schottky diode must be added in parallel to the output. The function of this diode is integrated into the TPS6040x devices, which gives a defined startup performance and saves board space.

A current sink and a diode in series can approximate the behavior of a typical, modern operational amplifier. Figure 30 shows the current into this typical load at a given voltage. The TPS6040x devices are optimized to start into these loads.

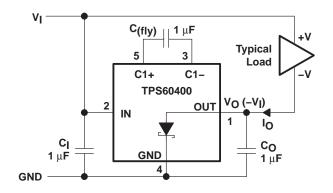


Figure 30. Typical Load

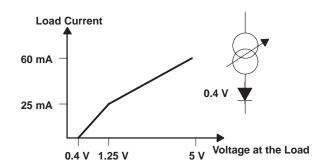


Figure 31. Maximum Start-Up Current

## shutting down the TPS6040x

If shutdown is necessary, use the circuit in Figure 32. The output resistance of the TPS6040x will typically be 15  $\Omega$  plus two times the output resistance of the buffer.

Connecting multiple buffers in parallel can reduce the output resistance of the buffer driving the IN pin.

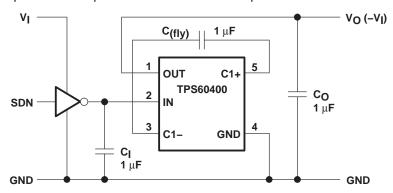


Figure 32. Shutdown Control

## **GaAs supply**

A solution for a -2.7-V/3-mA GaAs bias supply is proposed in Figure 33. The input voltage of 3.3 V is first inverted with a TPS60403 and stabilized using a TLV431 low-voltage shunt regulator. Resistor R<sub>P</sub> with capacitor C<sub>P</sub> is used for filtering the output voltage.

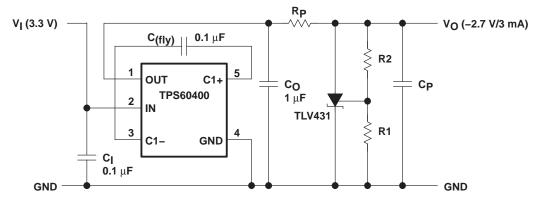


Figure 33. GaAs Supply

$$V_{O} = -\left(1 + \frac{R1}{R2}\right) \times V_{ref} - R1 \times I_{I(ref)}$$

A 0.1- $\mu$ F capacitor was selected for C<sub>(flv)</sub>. By this, the output resistance of the inverter is about 52  $\Omega$ .

## GaAs supply (continued)

R<sub>PMAX</sub> can be calculated using the following equation:

$$R_{PMAX} = \left(\frac{V_{CO} - V_{O}}{I_{O}} - R_{O}\right)$$

With: 
$$V_{CO} = -3.3 \text{ V}$$
;  $V_{O} = -2.7 \text{ V}$ ;  $I_{O} = -3 \text{ mA}$ 

$$R_{PMAX} = 200 \Omega - 52 \Omega = 148 \Omega$$

A 100- $\Omega$  resistor was selected for R<sub>P</sub>.

The reference voltage across R2 is 1.24 V typical. With 5-µA current for the voltage divider, R2 gets:

$$R2 = \frac{1.24 \text{ V}}{5 \text{ µA}} \approx 250 \text{ k}\Omega$$

$$R1 = \frac{2.7 - 1.24 \text{ V}}{5 \,\mu\text{A}} \approx 300 \text{ k}\Omega$$

With  $C_P = 1 \mu F$  the ratio  $V_O/V_I$  of the RC post filter is:

$$\left| \frac{V_{O}}{V_{I}} \right| = \frac{1}{\sqrt{1 + (2\pi 125000 \text{Hz} \times 100\Omega \times 1 \,\mu\text{F})^{2}}} \approx 0.01$$

#### step-down charge pump

By exchanging GND with OUT (connecting the GND pin with OUT and the OUT pin with GND), a step-down charge pump can easily be formed. In the first cycle S1 and S3 are closed, and  $C_{(fly)}$  with  $C_O$  in series are charged. Assuming the same capacitance, the voltage across  $C_{(fly)}$  and  $C_O$  is split equally between the capacitors. In the second cycle, S2 and S4 close and both capacitors with  $V_I/2$  across are connected in parallel.

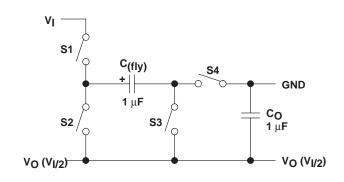


Figure 34. Step-Down Principle

Figure 35. Step-Down Charge Pump Connection

The maximum input voltage between  $V_I$  and GND in the schematic (or between IN and OUT at the device itself) must not exceed 6.5 V. For input voltages in the range of 6.5 V to 11 V, an additional Zener-diode is recommended (see Figure 36).



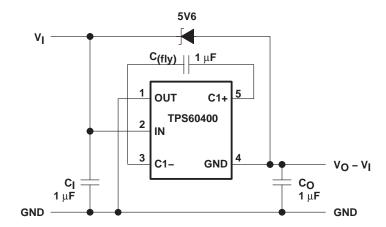


Figure 36. Step-Down Charge Pump Connection With Additional Zener Diode

## power dissipation

As given in this data sheet, the thermal resistance of the unsoldered package is  $R_{\theta JA} = 347^{\circ}$ C/W. Soldered on the EVM, a typical thermal resistance of  $R_{\theta JA(EVM)} = 180^{\circ}$ C/W was measured.

The terminal resistance can be calculated using the following equation:

$$R_{\theta JA} = \frac{T_J - T_A}{P_D}$$

Where:

T<sub>J</sub> is the junction temperature.

T<sub>A</sub> is the ambient temperature.

P<sub>D</sub> is the power that needs to be dissipated by the device.

$$R_{\theta JA} = \frac{T_J - T_A}{P_D}$$

The maximum power dissipation can be calculated using the following equation:

$$P_D = V_I \times I_I - V_O \times I_O = V_{I(max)} \times (I_O + I_{(SUPPLY)}) - V_O \times I_O$$

The maximum power dissipation happens with maximum input voltage and maximum output current.

At maximum load the supply current is 0.7 mA maximum.

$$P_D = 5 \text{ V} \times (60 \text{ mA} + 0.7 \text{ mA}) - 4.4 \text{ V} \times 60 \text{ mA} = 40 \text{ mW}$$

With this maximum rating and the thermal resistance of the device on the EVM, the maximum temperature rise above ambient temperature can be calculated using the following equation:

$$\Delta T_J = R_{\theta,JA} \times P_D = 180^{\circ}C/W \times 40 \text{ mW} = 7.2^{\circ}C$$

This means that the internal dissipation increases T<sub>J</sub> by <10°C.

The junction temperature of the device shall not exceed 125°C.

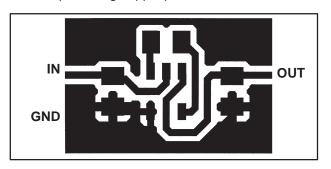
This means the IC can easily be used at ambient temperatures up to:

$$T_A = T_{J(max)} - \Delta T_J = 125^{\circ}C/W - 10^{\circ}C = 115^{\circ}C$$



## layout and board space

All capacitors should be soldered as close as possible to the IC. A PCB layout proposal for a single-layer board is shown in Figure 37. Care has been taken to connect all capacitors as close as possible to the circuit to achieve optimized output voltage ripple performance.



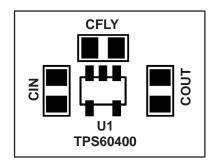


Figure 37. Recommended PCB Layout for TPS6040x (Top Layer)

## device family products

Other inverting dc-dc converters from Texas Instruments are listed in Table 5.

**Table 5. Product Identification** 

PART NUMBER	DESCRIPTION
TPS6735	Fixed negative 5-V, 200-mA inverting dc-dc converter
TPS6755	Adjustable 1-W inverting dc-dc converter





11-Apr-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
TPS60400QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AWP	Samples
TPS60401QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AWQ	Samples
TPS60402QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AWR	Samples
TPS60403QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AWS	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.





11-Apr-2013

### OTHER QUALIFIED VERSIONS OF TPS60400-Q1, TPS60401-Q1, TPS60402-Q1, TPS60403-Q1:

• Catalog: TPS60400, TPS60401, TPS60402, TPS60403

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

## PACKAGE MATERIALS INFORMATION

www.ti.com 14-Mar-2013

## TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All difficults are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS60400QDBVRQ1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS60401QDBVRQ1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS60402QDBVRQ1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS60403QDBVRQ1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS60400QDBVRQ1	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS60401QDBVRQ1	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS60402QDBVRQ1	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS60403QDBVRQ1	SOT-23	DBV	5	3000	182.0	182.0	20.0

DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



## DBV (R-PDSO-G5)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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